



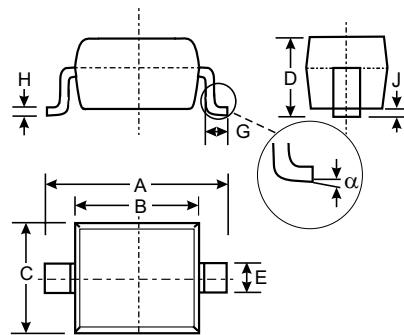
**烜芯微**  
XUANXINWEI

# B5817WS-B5819WS

## 1.0A Schottky Barrier Diode

### ■ Features

- For use in low voltage, high frequency inverters
- Free wheeling, and polarity protection applications.



SOD-323		
Dim	Min	Max
A	2.30	2.70
B	1.60	1.80
C	1.20	1.40
D	1.05 Typical	
E	0.25	0.35
G	0.20	0.40
H	0.10	0.15
J	0.05 Typical	
$\alpha$	0°	8°
All Dimensions in mm		

### ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	B5817WS	B5818WS	B5819WS	Unit
Non-Repetitive Peak reverse voltage	V RM	20	30	40	V
Peak repetitive Peak reverse voltage	V RRM				
Working Peak Reverse Voltage	V RWM	20	30	40	V
DC Blocking Voltage	V R				
RMS Reverse Voltage	V R(RMS)	14	21	28	V
Average Rectified Output Current	I O		1		A
Peak forward surge current @=8.3ms	I FSM		25		A
Repetitive Peak Forward Current	I FPM		625		mA
Power Dissipation	P d		250		mW
Thermal Resistance Junction to Ambient	R $\theta$ JA		500		K/W
Storage temperature	T STG		-55 to 150		°C

### ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Reverse breakdown voltage B5817WS B5818WS B5819WS	V(BR)	IR= 1mA	20 30 40			V
Reverse voltage leakage current B5817WS B5818WS B5819WS	IR	VR=20V VR=30V VR=40V			1	mA
Forward voltage B5817WS B5818WS B5819WS	VF	IF=1A IF=3A IF=1A IF=3A IF=1A IF=3A			0.45 0.75 0.55 0.875 0.6 0.9	V
Diode capacitance	CD	VR=4V, f=1MHz			120	pF

### ■ Marking

NO.	B5817WS	B5818WS	B5819WS
Marking	SJ	SK	SL

## ■ Typical Characteristics

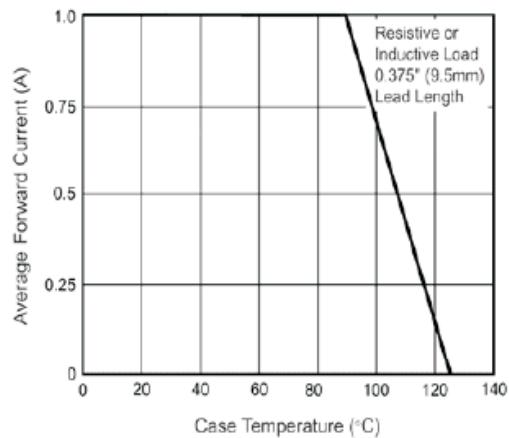


Fig.1 Forward Current Derating Curve

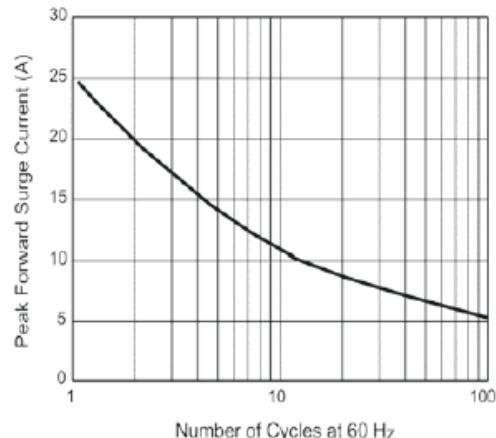


Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

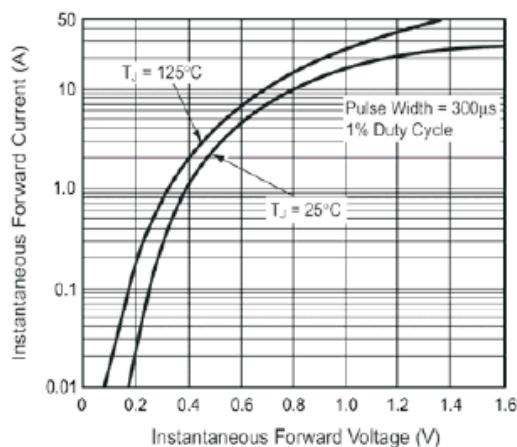


Fig.3 Typical Instantaneous Forward Characteristics

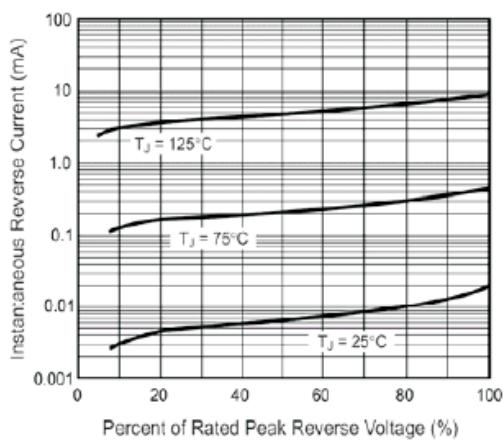


Fig.4 Typical Reverse Characteristics

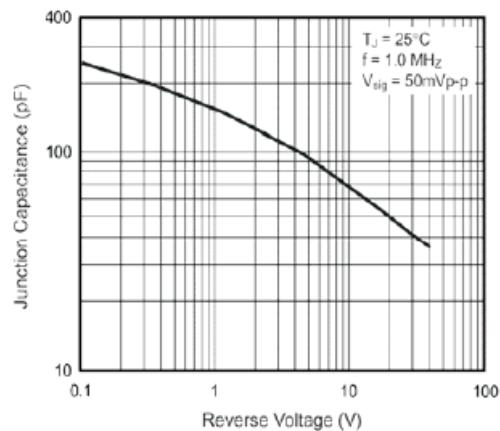


Fig.5 Typical Junction Capacitance

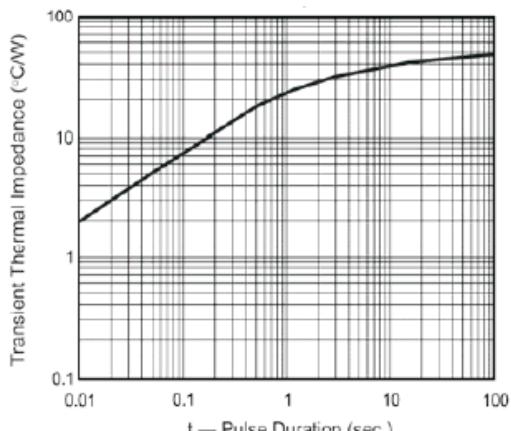


Fig.6 Typical Transient Thermal Impedance